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Hyperfast Rectifier, 75 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES

A

Application Notes



PRIMARY CHARACTERISTICS				
I _{F(AV)}	75 A			
V _R	1200 V			
V _F at I _F at 125 °C	1.85 V			
t _{rr}	40 ns			
T _J max.	175 °C			
Package	TO-247AD 2L			
Circuit configuration	Single			

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- AEC-Q101 gualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Repetitive peak reverse voltage	V _{RRM}		1200	V	
Average rectified forward current	I _{F(AV)}	T _C = 103 °C, D = 0.50	75		
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	470	А	
Repetitive peak forward current	I _{FRM}	T _C = 103 °C, D = 0.50, f = 20 kHz	150		
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	MBOL TEST CONDITIONS MIN. TYP. M		MAX.	UNITS	
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	1200	-	-	
Forward valtage	V	I _F = 75 A	-	2.0	2.6	V
Forward voltage V _F	۷F	I _F = 75 A, T _J = 125 °C	-	1.85	-	
	1	V _R = V _R rated	-	-	50	
Reverse leakage current I _R		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA
Junction capacitance	C _T V _R = 200 V		-	36	-	pF
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	40	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	145	-	ns	
		T _J = 125 °C		-	220	-		
Poak recevery current	1	T _J = 25 °C	I _F = 50 A dI _F /dt = 600 A/μs V _R = 400 V	-	24	-	A	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	43	-		
Deserves and have	0	T _J = 25 °C		-	1710	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	4820	-	no	
	+	T _J = 25 °C		-	115	-	ns	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	165	-	115	
Peak recovery current I _R	I _{RRM}	T _J = 25 °C	I _F = 75 A dI _F /dt = 1000 A/μs V _B = 800 V	-	42	-	А	
		T _J = 125 °C		-	72	-	~	
Reverse recovery charge	Q _{rr}		T _J = 25 °C		-	2780	-	nC
		T _J = 125 °C		-	7100	-		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.36	°C/W
Weight			-	5.5	-	g
weight			-	0.2	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Marking device		Case style TO-247AD 2L		E5PH7	7512LH	

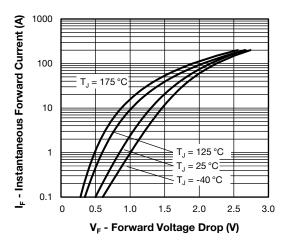


Fig. 1 - Forward Voltage Drop Characteristics

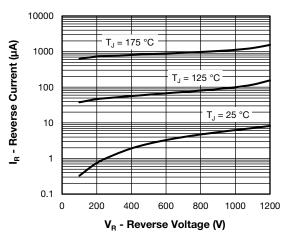


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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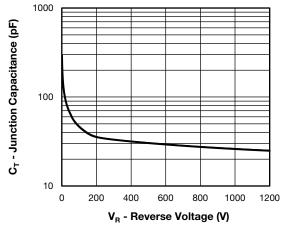


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

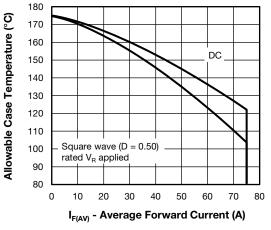


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

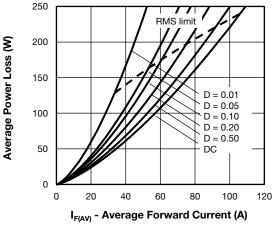


Fig. 5 - Forward Power Loss Characteristics

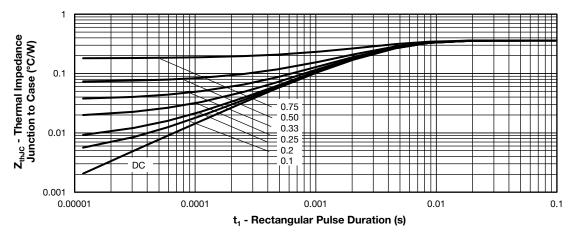
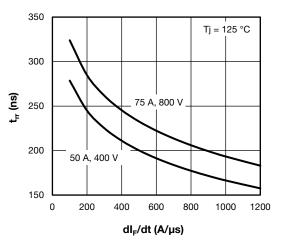


Fig. 6 - Transient Thermal Impedance, Junction to Case

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Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

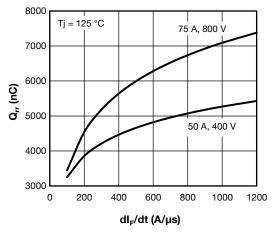


Fig. 8 - Typical Reverse Recovery Charge vs. dI_F/dt

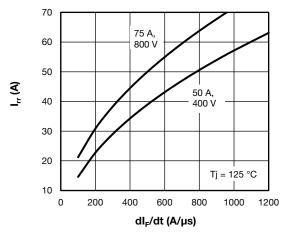


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt



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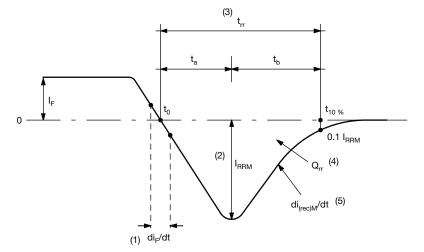


Fig. 10 - Reverse Recovery Waveform and Definitions

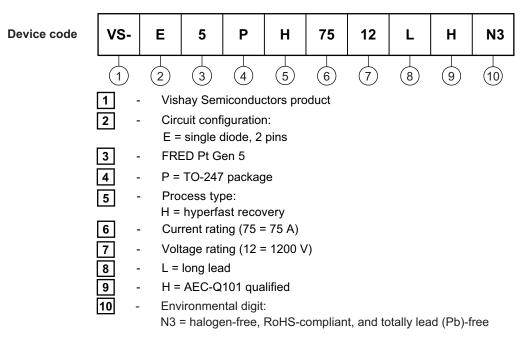
Notes

- ⁽¹⁾ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{10\%}$, 0.1 I_{RRM} (4) Q_{rr} area under curve defined by t_0 and $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

⁽⁵⁾ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



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ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-E5PH7512LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95536
Part marking information	www.vishay.com/doc?95648



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